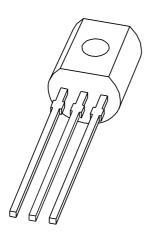
DISCRETE SEMICONDUCTORS

DATA SHEET



JC327 PNP general purpose transistor

Product specification Supersedes data of 1999 Apr 27

2004 Dec 08





PNP general purpose transistor

JC327

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 45 V).

APPLICATIONS

• General purpose switching and amplification, e.g. driver and output stages of audio amplifiers.

DESCRIPTION

PNP transistor in a TO-92; SOT54 plastic package. NPN complement: JC337.

PINNING

PIN	DESCRIPTION				
1	base				
2	collector				
3	emitter				

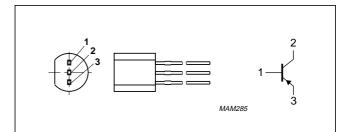


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE NAME DESCRIPTION VERSION					
ITPE NOWIBER						
JC327-25	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

PNP general purpose transistor

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-50	V
V _{CEO}	collector-emitter voltage	open base; I _C = −10 mA	_	-45	V
V _{EBO}	emitter-base voltage	open collector	_	- 5	V
I _C	collector current (DC)		_	-500	mA
I _{CM}	peak collector current		_	-1	А
I _{BM}	peak base current		_	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	625	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	200	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
		$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	_	_	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	_	_	-100	nA
h _{FE}	DC current gain	V _{CE} = -1 V				
		$I_{\rm C} = -100 \text{ mA}$	160	_	400	
		I _C = −500 mA	40	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	_	_	-700	mV
V _{BE}	base-emitter voltage	$V_{CE} = -1 \text{ V; } I_{C} = -500 \text{ mA; note 1}$	_	_	-1.2	V
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	_	8	_	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA};$ f = 100 MHz	80	_	_	MHz

Note

1. V_{BE} decreases by about –2 mV/K with increasing temperature.

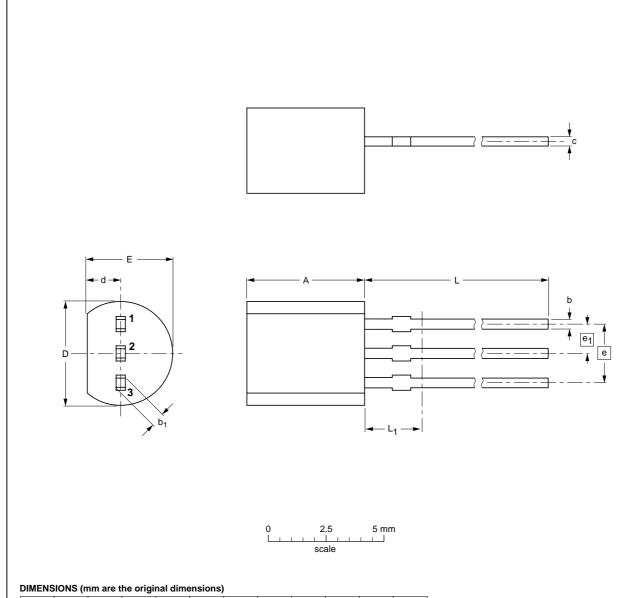
PNP general purpose transistor

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			04-06-28 04-11-16

PNP general purpose transistor

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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